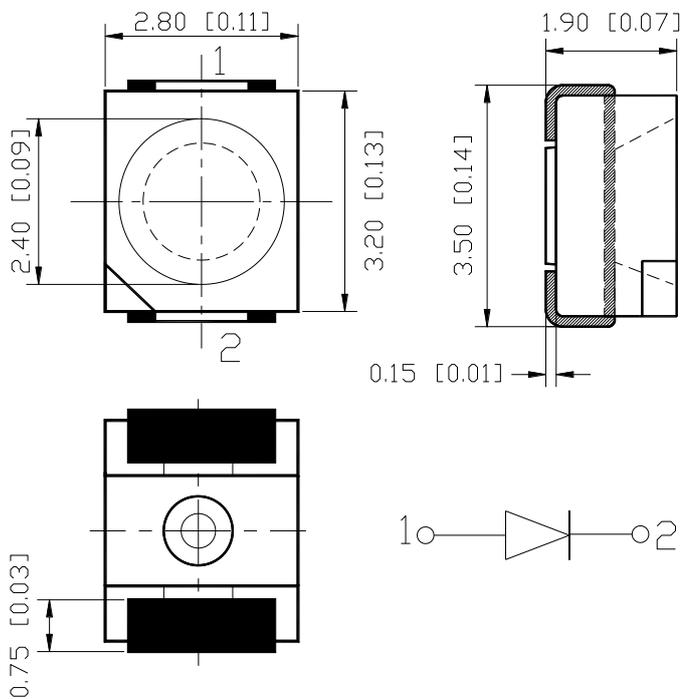


BRIGHTEK OPTOELECTRONICS

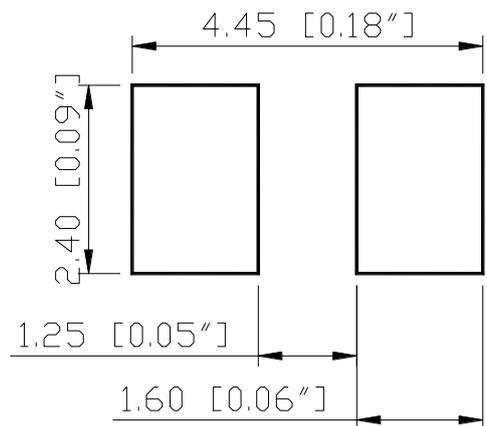
INFRARED EMITTING DIODE

Part Number: N0F18S15

Package outlines



RECOMMEND PAD LAYOUT



ITEM	MATERIALS
Resin	Silicon
Lens color	Water transparent
Dice	AlGaAs/AlGaAs
Emitted color	Infrared

NOTES:

1. All dimensions are in millimeters (inches);
2. Tolerances are $\pm 0.2\text{mm}$ (0.008inch) unless otherwise noted.

Rev :	Date	Drawn by :	Checked by :	Approved by :
A	2013/01/31			

BRIGHTEK OPTOELECTRONICS

INFRARED EMITTING DIODE

Part Number: N0F18S15

Absolute maximum ratings (T_A=25°C)

Parameter	Symbol	Value	Unit
Power dissipation	Pd	90	mW
Peak forward current Pulse width 100μs, duty cycle =1%	I _{fp}	1	A
Continuous forward current	I _f	100	mA
Reverse voltage	V _r	5	V
Operating temperature range	T _{op}	-40 ~+80	°C
Storage temperature range	T _{stg}	-40 ~+85	°C

Electro-optical characteristics (T_A=25°C)

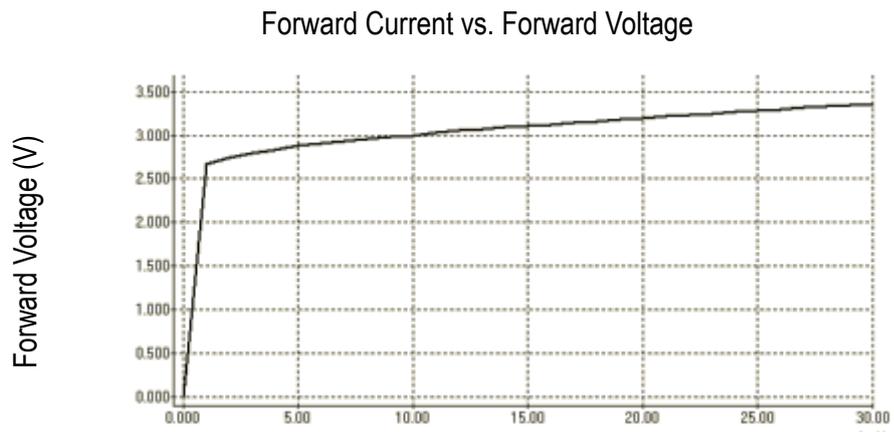
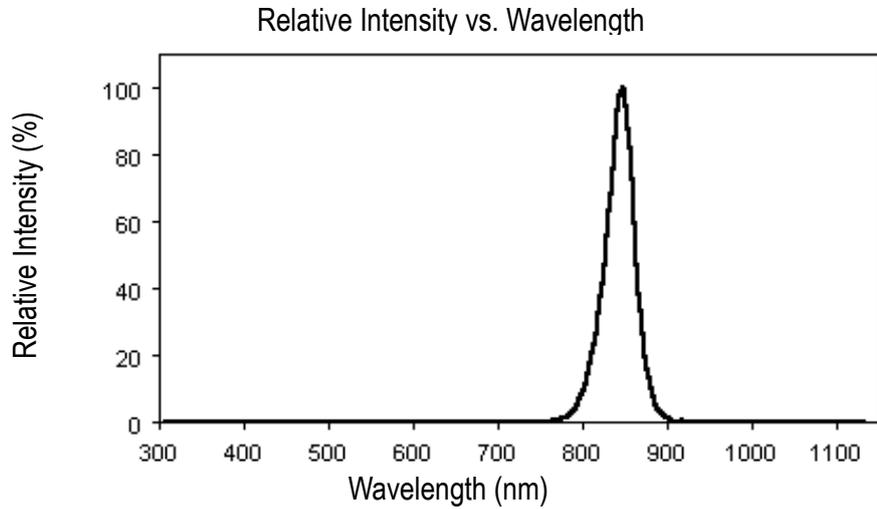
Parameter	Test Condition	Symbol	Value			Unit
			Min	Typ	Max	
Radiated intensity	I _f =50mA	I _e	3.10	5.0	6.6	mW/sr
Forward voltage	I _f =50mA	V _f	1.00	1.40	1.80	V
Peak wavelength	I _f =50mA	λ _p	840	850	860	nm
Spectral bandwidth	I _f =50mA	Δλ	--	50	--	nm
Reverse current	V _r =5V	I _r	--	--	10	μA
View angle	I _f =20mA	2θ 1/2	--	120	--	Deg

BRIGHTTEK OPTOELECTRONICS

INFRARED EMITTING DIODE

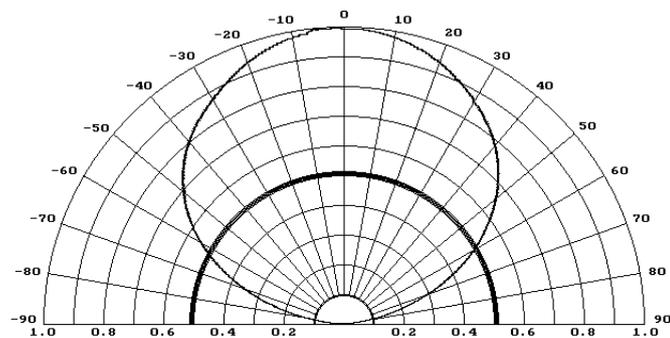
Part Number: N0F18S15

OPTICAL CHARACTERISTIC CURVES



Forward Current (mA)

Directive Characteristics

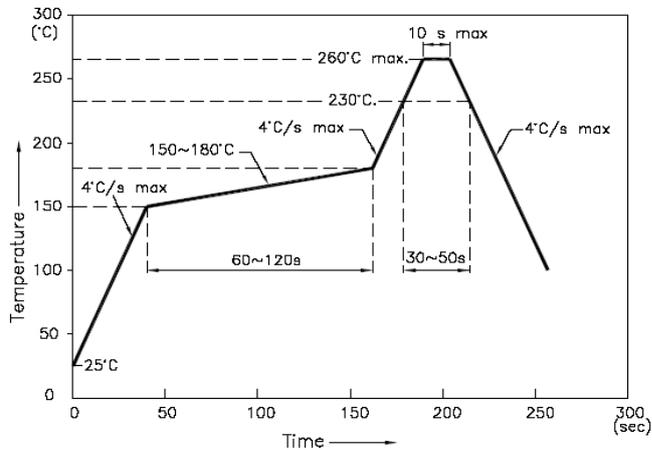


BRIGHTEK OPTOELECTRONICS

INFRARED EMITTING DIODE

Reflow Profile

■ Reflow Temp/Time



NOTES:

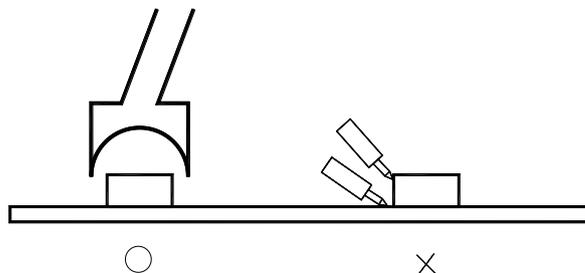
1. We recommend the reflow temperature $245^{\circ}\text{C} (\pm 5^{\circ}\text{C})$. the maximum soldering temperature should be limited to 260°C .
2. dont cause stress to the epoxy resin while it is exposed to high temperature.
3. Number of reflow process shall be 2 times or less.

■ Soldering iron

Basic spec is $\leq 5\text{sec}$ when 260°C . If temperature is higher, time should be shorter ($+10^{\circ}\text{C} \rightarrow -1\text{sec}$). Power dissipation of iron should be smaller than 20W, and temperatures should be controllable. Surface temperature of the device should be under 230°C .

■ Rework

1. Customer must finish rework within 5 sec under 260°C .
2. The head of iron can not touch copper foil
3. Twin-head type is preferred.



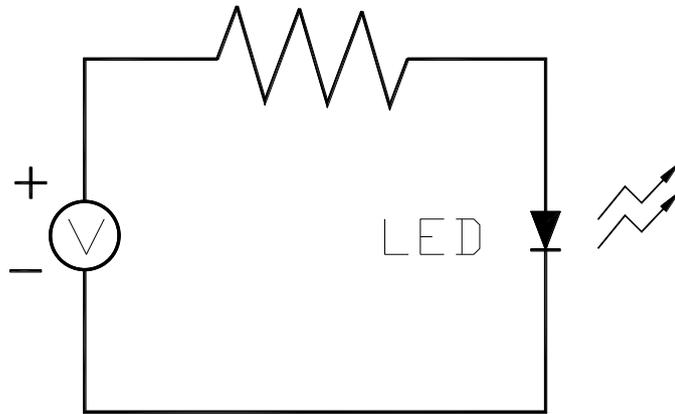
- Avoid rubbing or scraping the resin by any object, during high temperature, for example reflow 、 solder etc.

BRIGHTEK OPTOELECTRONICS

INFRARED EMITTING DIODE

Test circuit and handling precautions

■ Test circuit



■ Handling precautions

1. Over-current-proof

Customer must apply resistors for protection; otherwise slight voltage shift will cause big current change (Burn out will happen).

2. Shelf life in sealed bag: 12 months at $5^{\circ}\text{C}\sim 30^{\circ}\text{C}$ and $< 60\% \text{ R.H.}$;

3. After the package is Opened:

3.1. It is recommended to baking before the first use:

Baking condition:

a. $60\pm 3^{\circ}\text{C}$ x (36~48hrs) and $< 5\% \text{RH}$, taped reel type ;

b. $110\pm 3^{\circ}\text{C}$ x (8~16hr), bulk type ;

3.2 The products should be used within a week:

a. It is recommended to baking before soldering when the pack is unsealed after 72hrs ;

b. Baking condition as 3.1 baking condition.

BRIGHTTEK OPTOELECTRONICS

INFRARED EMITTING DIODE

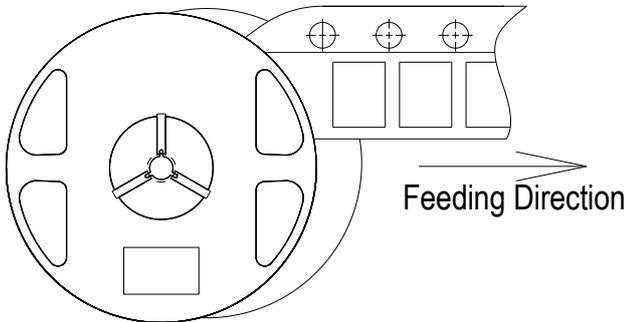
Test items and results of reliability

Type	Test Item	Test Conditions	Note	Number of Damaged
Environmental Sequence	Temperature Cycle	-20°C 30min ↑ ↓ 80°C 30min	100 cycle	0/22
	Thermal Shock	-20°C 15min ↑ ↓ 80°C 15min	100 cycle	0/22
	High Humidity Heat Cycle	30°C ↔ 65°C 90%RH 24hrs/1cycle	10 cycle	0/22
	High Temperature Storage	T _a =80°C	1000 hrs	0/22
	Humidity Heat Storage	T _a =60°C RH=90%	1000 hrs	0/22
	Low Temperature Storage	T _a =-30°C	1000 hrs	0/22
Operation Sequence	Life Test	T _a =25°C I _F =20mA	1000 hrs	0/22
	High Humidity Heat Life Test	60°C RH=90% I _F =10mA	500 hrs	0/22
	Low Temperature Life Test	T _a =-20°C I _F =20mA	1000 hrs	0/22

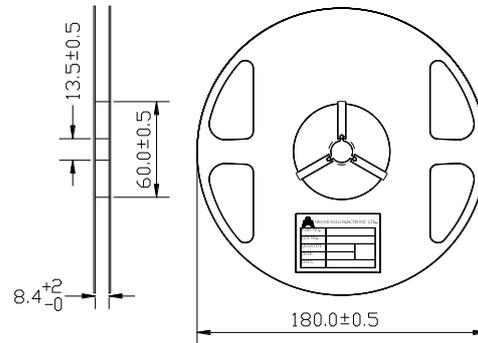
PACKAGING SPECIFICATIONS

High Performance SMD Top LEDs Packaging Specifications

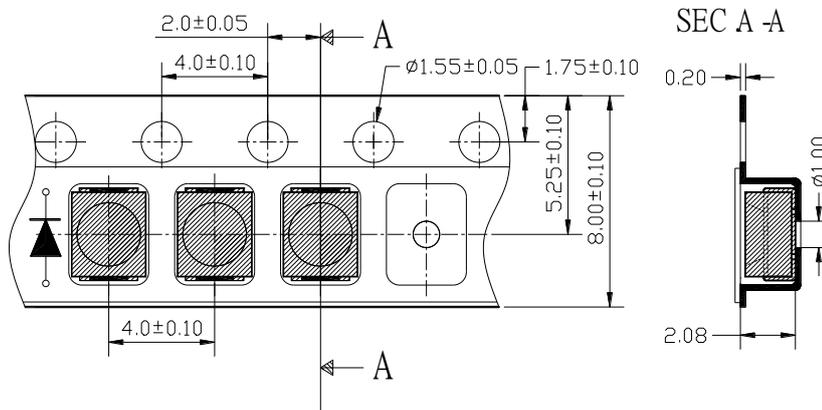
● Feeding Direction



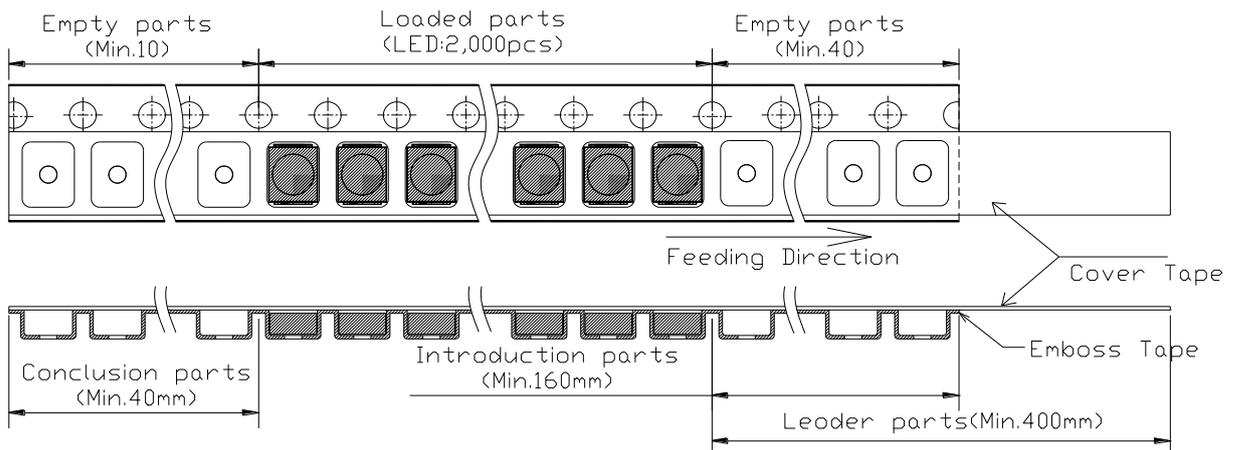
● Dimensions of Reel (Unit: mm)



● Dimensions of Tape (Unit: mm)



● Arrangement of Tape

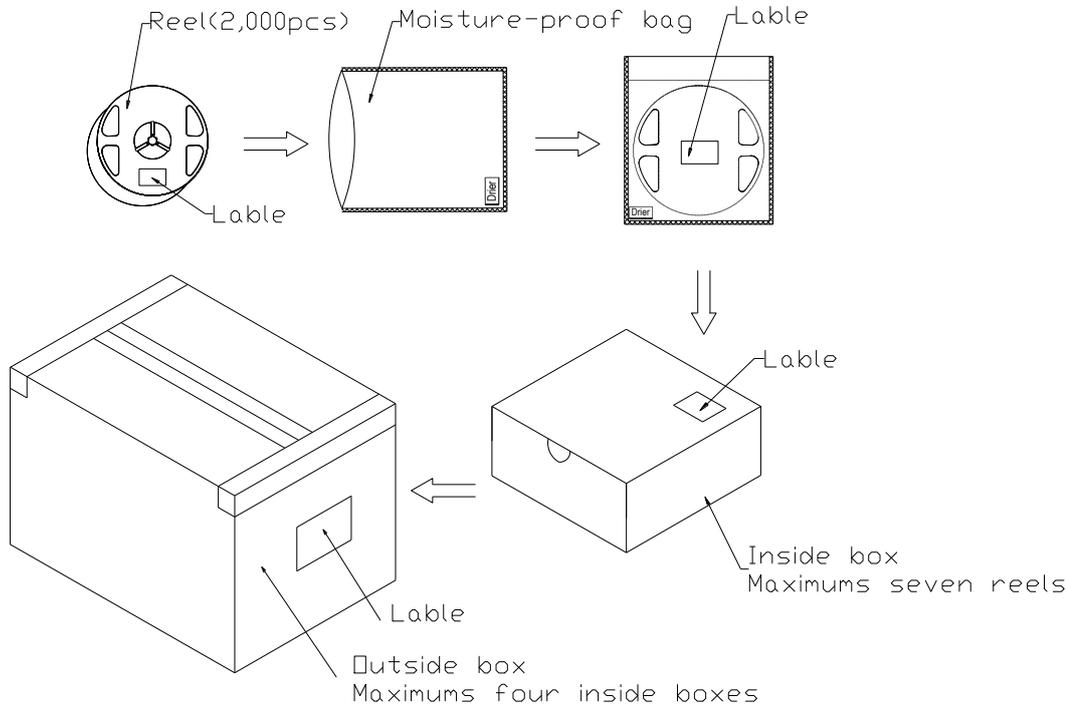


NOTES

1. Empty component pockets are sealed with top cover tape;
2. The maximum number of missing lamps is two;
3. The cathode is oriented towards the tape sprocket hole;
4. 2,000pcs/Reel

High Performance SMD Top LEDs Packaging Specifications

- Packaging specifications



NOTES:

Reeled products (numbers of products are 2,000pcs) packed in a seal off moisture-proof bag along with a desiccant one by one, Seven moisture-proof bag of maximums (total maximum number of products are 14,000pcs) packed in an inside box (size: about 238mm x about 194mm x about 102mm) and four inside boxes of maximums are put in the outside box (size: about 410mm x about 254mm x about 229mm) Together with buffer material, and it is packed. (Part No., Lot No., quantity should appear on the label on the moisture-proof bag, part No. And quantity should appear on the label on the cardboard box.) The number of the loading steps of outside box (cardboard box) has it to three steps.

BRIGHTTEK OPTOELECTRONICS

INFRARED EMITTING DIODE

Part Number: N0F18S15

Forward Voltage Rank Combination (IF=50mA)

Rank	Min.	Max.	Unit
□	1.00	1.80	V

Radiant Intensity Rank Combination (IF=50mA)

Rank	Min.	Max.	Unit
G	3.10	3.60	mW/sr
H	3.60	4.10	
I	4.10	4.60	
J	4.60	5.10	
K	5.10	5.60	
L	5.60	6.10	
M	6.10	6.60	

Peak wavelength Rank Combination (IF=50mA)

Rank	Min.	Max.	Unit
□	840	860	nm

Group Name on Label (Example DATA: □J□ 50)

DATA: □J□ 50	Vf(V)	Ie (mW/Sr)	λ p (nm)	Test Condition
□ → J → □ → 50	1.00~1.80	4.60~5.10	840~860	IF=50mA

※ NOTE:

1. The tolerance of Radiant incidence (Ie)is ±15% .
2. The tolerance of Peak wavelength is ±1nm.
3. This specification is preliminary.